

BYV29-600

Rectifier diode ultrafast

Rev. 02 — 24 October 2007

Product data sheet

1. Product profile

1.1 General description

Ultrafast, epitaxial rectifier diode in a SOD59 (TO-220AC) plastic package.

1.2 Features

- Fast switching
- Soft recovery characteristic
- Low forward voltage drop
- Low thermal resistance
- High thermal cycling performance

1.3 Applications

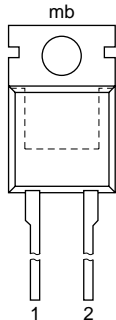

- High frequency switched-mode power supplies
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

1.4 Quick reference data

- $V_{RRM} \leq 600 \text{ V}$
- $V_F \leq 1.11 \text{ V}$
- $I_{F(AV)} \leq 9 \text{ A}$
- $t_{rr} \leq 60 \text{ ns}$

2. Pinning information

Table 1. Pinning

| Pin | Description | Simplified outline | Symbol |
|-----|------------------------|--|--|
| 1 | cathode (k) |  |  001aaa020 |
| 2 | anode (a) | | |
| mb | mounting base; cathode | | |

SOD59 (2-lead TO-220AC)

3. Ordering information

Table 2. Ordering information

| Type number | Package | | | Version |
|-------------|----------|--|--|---------|
| | Name | Description | | |
| BYV29-600 | TO-220AC | plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC | | SOD59 |

4. Limiting values

Table 3. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--------------------|-------------------------------------|---|-----|------|------|
| V _{RRM} | repetitive peak reverse voltage | | - | 600 | V |
| V _{RWM} | crest working reverse voltage | | - | 600 | V |
| V _R | reverse voltage | square waveform; $\delta = 1.0$; $T_{mb} \leq 100\text{ }^{\circ}\text{C}$ | - | 600 | V |
| I _{F(AV)} | average forward current | square waveform; $\delta = 0.5$; $T_{mb} \leq 120\text{ }^{\circ}\text{C}$ | - | 9 | A |
| I _{FRM} | repetitive peak forward current | square waveform; $\delta = 0.5$; $T_{mb} \leq 120\text{ }^{\circ}\text{C}$ | - | 18 | A |
| I _{FSM} | non-repetitive peak forward current | t = 10 ms; sinusoidal waveform | - | 70 | A |
| | | t = 8.3 ms; sinusoidal waveform | - | 77 | A |
| T _{stg} | storage temperature | | -40 | +150 | °C |
| T _j | junction temperature | | - | 150 | °C |

5. Thermal characteristics

Table 4. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------------|---|--|-----|-----|-----|------|
| R _{th(j-mb)} | thermal resistance from junction to mounting base | with heatsink compound; see Figure 1 | - | - | 2.5 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |

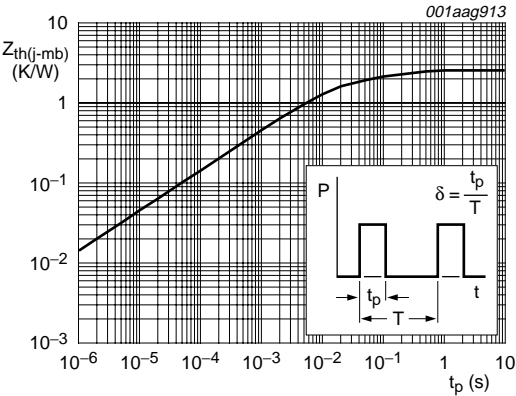
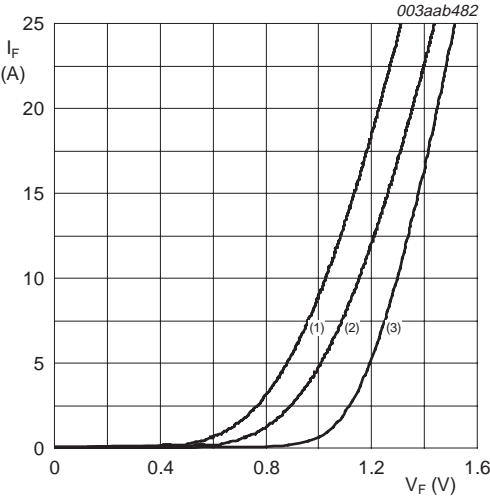


Fig 1. Transient thermal impedance from junction to mounting base as a function of pulse width

6. Characteristics

Table 5. Characteristics
T_j = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------|-------------------------------|--|-----|------|------|------|
| Static characteristics | | | | | | |
| V _F | forward voltage | I _F = 8 A; T _j = 150 °C; see Figure 2 | - | 0.97 | 1.11 | V |
| | | I _F = 8 A | - | 1.12 | 1.25 | V |
| | | I _F = 20 A; see Figure 2 | - | 1.31 | 1.45 | V |
| I _R | reverse current | V _R = 600 V | - | 2 | 50 | μA |
| | | V _R = 600 V; T _j = 100 °C | - | 0.1 | 0.35 | mA |
| Dynamic characteristics | | | | | | |
| Q _r | recovered charge | I _F = 2 A to V _R ≥ 30 V; dI _F /dt = 20 A/μs; see Figure 3 | - | 40 | 70 | nC |
| t _{rr} | reverse recovery time | I _F = 1 A to V _R ≥ 30 V; dI _F /dt = 100 A/μs; see Figure 3 | - | 50 | 60 | ns |
| I _{RM} | peak reverse recovery current | I _F = 10 A to V _R ≥ 30 V; dI _F /dt = 50 A/μs; T _j = 100 °C; see Figure 3 | - | 3 | 5.5 | A |
| V _{FR} | forward recovery voltage | I _F = 10 A; dI _F /dt = 10 A/μs; see Figure 4 | - | 3.2 | - | V |



- (1) T_j = 150 °C; typical values
- (2) T_j = 150 °C; maximum values
- (3) T_j = 25 °C; maximum values

Fig 2. Forward current as a function of forward voltage

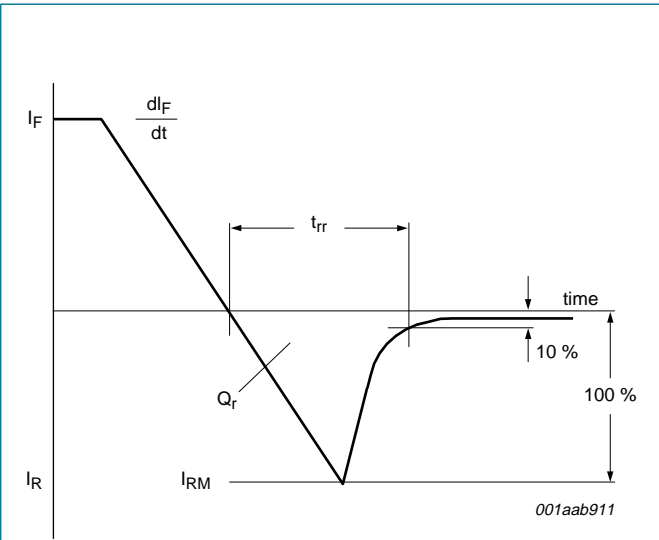


Fig 3. Reverse recovery definitions

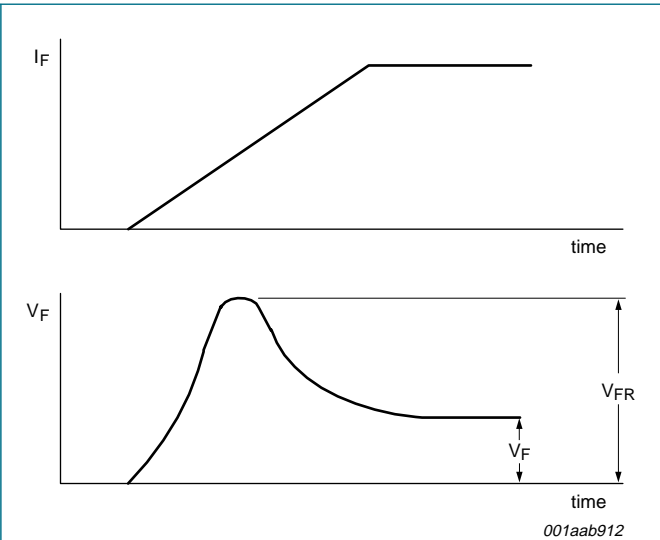


Fig 4. Forward recovery definitions

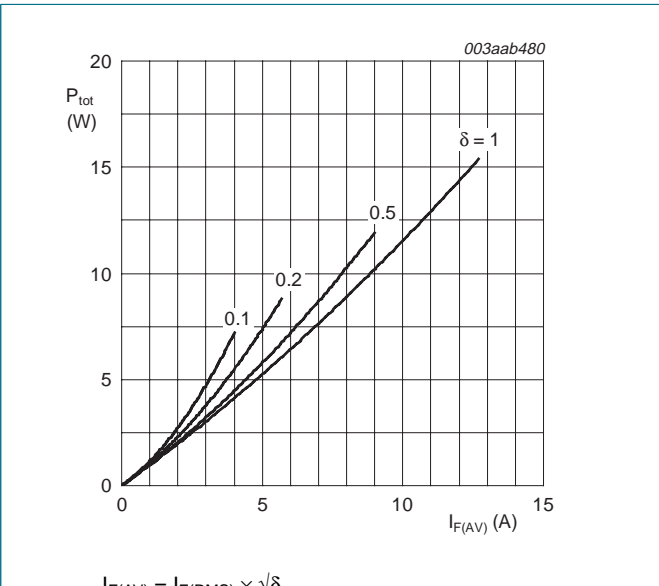


Fig 5. Forward power dissipation as a function of average forward current; square waveform; maximum values

$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

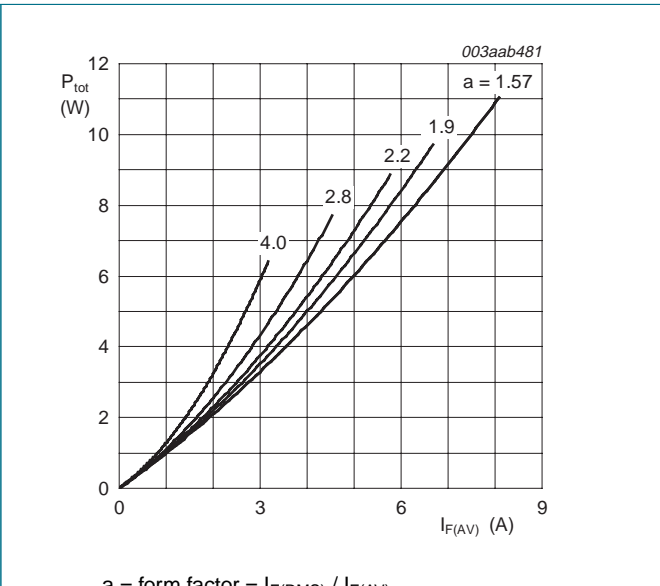


Fig 6. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

$$a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$$

7. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC

SOD59

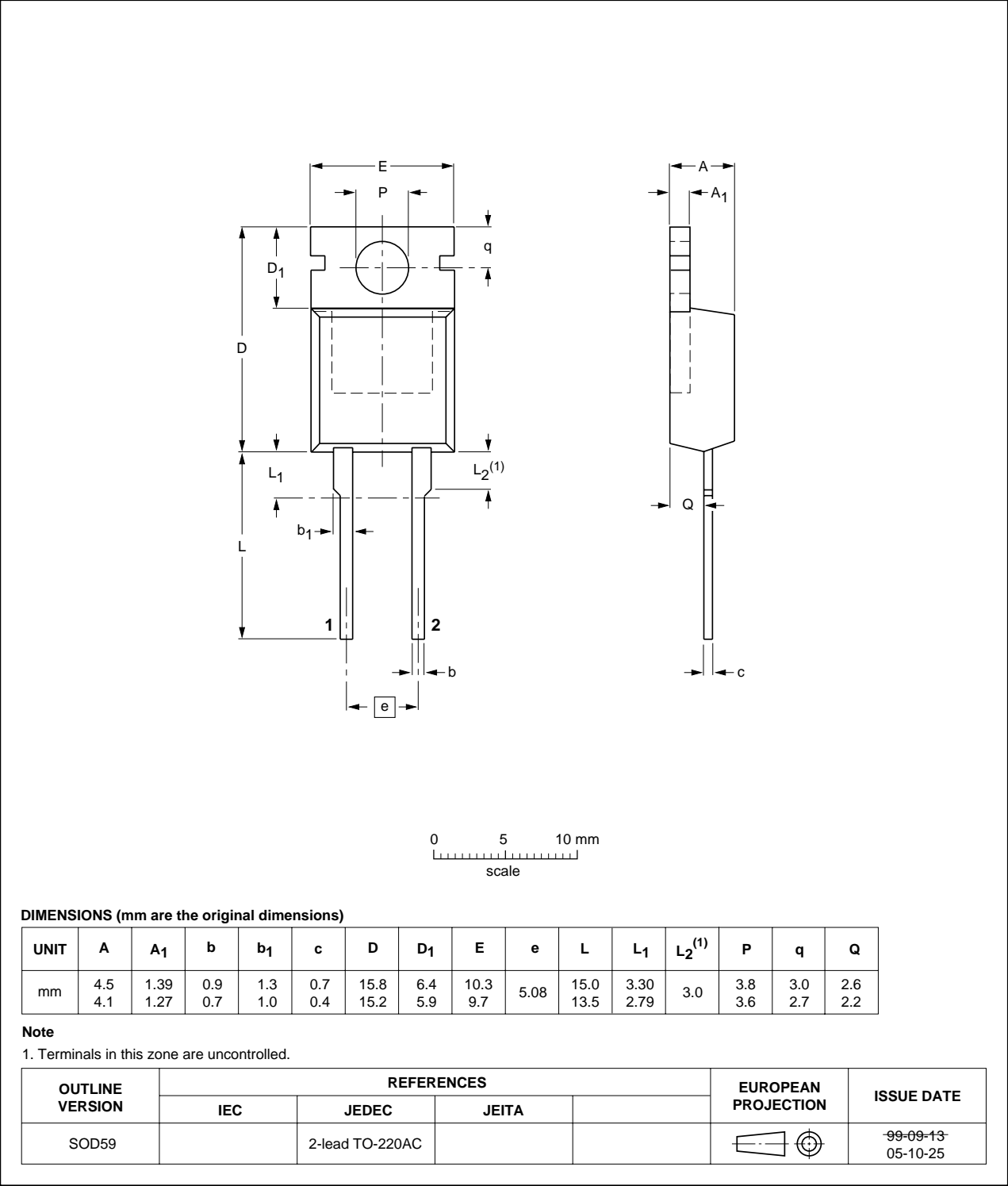


Fig 7. Package outline SOD59 (2-lead TO-220AC)

8. Revision history

Table 6. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--|-----------------------|---------------|-------------|
| BYV29-600_2 | 20071024 | Product data sheet | - | BYV29-600_1 |
| Modifications: | <ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.• Legal texts have been adapted to the new company name where appropriate.• Table 5 "Characteristics" on page 3: V_F values updated. | | | |
| BYV29-600_1 | 20000201 | Product specification | - | - |

9. Legal information

9.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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